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FAIRCHILD

SEMICONDUCTOR®

FDS8984 N-Channel PowerTrench[®] MOSFET

30V, 7A, $23m\Omega$

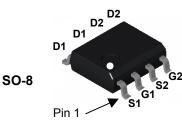
General Description

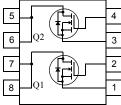
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{\text{DS}(\text{ON})}$ and fast switching speed.

Features

- Max $r_{DS(on)}$ = 23m Ω , V_{GS} = 10V, I_D = 7A
- Max $r_{DS(on)}$ = 30mΩ, V_{GS} = 4.5V, I_D = 6A
- Low gate charge
- 100% R_G tested
- RoHS Compliant







MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V _{DS}	Drain to Source Voltage		30	V	
V _{GS}	Gate to Source Voltage		±20	V	
1	Drain Current Continuous	(Note 1a)	7	А	
I _D	Pulsed		30	А	
E _{AS}	Single Pulse Avalache Energy	(Note 2)	32	mJ	
D	Power Dissipation for Single Operation		1.6	W	
P _D	Derate above 25°C		13	mW/°C	
T _J , T _{STG}	Operating and Storage Temperature		-55 to 150	°C	
Therma	Characteristics				
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	40	°C/W	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS8984	FDS8984	SO-8	330mm	12mm	2500 units

FDS8984 N-Channel PowerTrench[®] MOSFET

May 2007

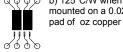
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	icteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	30			V
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to $25^{\circ}C$		23		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24V$ $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			1 250	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
	stariation (No. 4)					
	Icteristics (Note 3)		4.0	4 7	0.5	
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.2	1.7	2.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I _D = 250μA, referenced to 25°C		- 4.3		mV/°C
Ū		V _{GS} = 10V, I _D = 7A		19	23	mΩ
r	Drain to Source On Resistance	V _{GS} = 4.5V, I _D = 6A		24	30	
r _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V, I _D = 7A, T _J = 125°C		26	32	- 11152
Dynamic	Characteristics					
Ciec	Input Capacitance			475	635	pF
	Input Capacitance Output Capacitance	$V_{DS} = 15V, V_{GS} = 0V,$		475 100	635 135	
C _{oss}	Output Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz		100	135	pF
C _{oss} C _{rss} R _G	Output Capacitance Reverse Transfer Capacitance Gate Resistance					•
t _{d(on)} t _r	Output Capacitance Reverse Transfer Capacitance Gate Resistance g Characteristics (Note 3) Turn-On Delay Time Rise Time	f = 1.0MHz f = 1MHz V _{DD} = 15V, I _D = 7A		100 65 0.9 5 9	135 100 1.6 10 18	pF pF Ω ns ns
C _{oss} C _{rss} R _G Switching t _{d(on)} t _r t _{d(off)}	Output Capacitance Reverse Transfer Capacitance Gate Resistance Characteristics (Note 3) Turn-On Delay Time Rise Time Turn-Off Delay Time	f = 1.0MHz f = 1MHz		100 65 0.9 5 9 42	135 100 1.6 10 18 68	pF pF Ω ns ns ns
C _{oss} C _{rss} R _G Switching	Output Capacitance Reverse Transfer Capacitance Gate Resistance g Characteristics (Note 3) Turn-On Delay Time Rise Time	$f = 1.0MHz$ $f = 1MHz$ $V_{DD} = 15V, I_D = 7A$ $V_{GS} = 10V, R_{GS} = 33\Omega$ $V_{DS} = 15V, V_{GS} = 10V,$		100 65 0.9 5 9	135 100 1.6 10 18	pF pF Ω ns ns
C _{oss} C _{rss} R _G Switching t _{d(on)} t _r t _{d(off)} t _f Q _g	Output Capacitance Reverse Transfer Capacitance Gate Resistance 9 Characteristics (Note 3) Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time	$f = 1.0MHz$ $f = 1MHz$ $V_{DD} = 15V, I_D = 7A$ $V_{GS} = 10V, R_{GS} = 33\Omega$ $V_{DS} = 15V, V_{GS} = 10V,$ $I_D = 7A$		100 65 0.9 5 9 42 21	135 100 1.6 10 18 68 34	pF pF Ω ns ns ns ns
C _{oss} C _{rss} R _G Switching t _{d(on)} t _r t _{d(off)} t _f Q _g Q _g	Output Capacitance Reverse Transfer Capacitance Gate Resistance g Characteristics (Note 3) Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Total Gate Charge	$f = 1.0MHz$ $f = 1MHz$ $V_{DD} = 15V, I_D = 7A$ $V_{GS} = 10V, R_{GS} = 33\Omega$ $V_{DS} = 15V, V_{GS} = 10V,$		100 65 0.9 5 9 42 21 9.2	135 100 1.6 10 18 68 34 13	pF pF Ω ns ns ns ns nc
$\begin{array}{c} \hline C_{oss} \\ \hline C_{rss} \\$	Output Capacitance Reverse Transfer Capacitance Gate Resistance g Characteristics (Note 3) Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Total Gate Charge Total Gate Charge	$f = 1.0MHz$ $f = 1MHz$ $V_{DD} = 15V, I_D = 7A$ $V_{GS} = 10V, R_{GS} = 33\Omega$ $V_{DS} = 15V, V_{GS} = 10V,$ $I_D = 7A$ $V_{DS} = 15V, V_{GS} = 5V,$		100 65 0.9 5 9 42 21 9.2 5.0	135 100 1.6 10 18 68 34 13	pF pF Ω ns ns ns ns nc nC
C _{oss} C _{rss} R _G Switching t _{d(off)} t _f Q _g Q _g Q _{gs} Q _{gd}	Output Capacitance Reverse Transfer Capacitance Gate Resistance g Characteristics (Note 3) Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Total Gate Charge Gate to Source Gate Charge Gate to Drain "Miller" Charge	$f = 1.0MHz$ $f = 1MHz$ $V_{DD} = 15V, I_D = 7A$ $V_{GS} = 10V, R_{GS} = 33\Omega$ $V_{DS} = 15V, V_{GS} = 10V,$ $I_D = 7A$ $V_{DS} = 15V, V_{GS} = 5V,$		100 65 0.9 5 9 42 21 9.2 5.0 1.5	135 100 1.6 10 18 68 34 13	pF pF Ω ns ns ns ns nc nC nC
C _{oss} C _{rss} R _G Switching t _{d(on)} t _r t _{d(off)} t _f Q _g Q _g Q _g Q _{gs} Q _{gd} Drain-So	Output Capacitance Reverse Transfer Capacitance Gate Resistance g Characteristics (Note 3) Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Total Gate Charge Gate to Source Gate Charge Gate to Drain "Miller" Charge	$f = 1.0MHz$ $f = 1MHz$ $V_{DD} = 15V, I_D = 7A$ $V_{GS} = 10V, R_{GS} = 33\Omega$ $V_{DS} = 15V, V_{GS} = 10V,$ $I_D = 7A$ $V_{DS} = 15V, V_{GS} = 5V,$		100 65 0.9 5 9 42 21 9.2 5.0 1.5	135 100 1.6 10 18 68 34 13	pF pF Ω ns ns ns ns nc nC nC
C _{oss} C _{rss} R _G Switching t _{d(on)} t _r t _{d(off)} t _f Q _g Q _g Q _{gs} Q _{gd} Q _{gd} Drain-So	Output Capacitance Reverse Transfer Capacitance Gate Resistance g Characteristics (Note 3) Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Total Gate Charge Gate to Source Gate Charge Gate to Drain "Miller" Charge	$f = 1.0MHz$ $f = 1MHz$ $V_{DD} = 15V, I_D = 7A$ $V_{GS} = 10V, R_{GS} = 33\Omega$ $V_{DS} = 15V, V_{GS} = 10V,$ $I_D = 7A$ $V_{DS} = 15V, V_{GS} = 5V,$ $I_D = 7A$		100 65 0.9 5 9 42 21 9.2 5.0 1.5 2.0	135 100 1.6 10 18 68 34 13 7	pF pF Ω ns ns ns nc nC nC
C _{oss} C _{rss} R _G Switching t _{d(off)} t _f Q _g Q _g Q _{gs} Q _{gd}	Output Capacitance Reverse Transfer Capacitance Gate Resistance g Characteristics (Note 3) Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Total Gate Charge Gate to Source Gate Charge Gate to Drain "Miller" Charge	$f = 1.0MHz$ $f = 1MHz$ $V_{DD} = 15V, I_D = 7A$ $V_{GS} = 10V, R_{GS} = 33\Omega$ $V_{DS} = 15V, V_{GS} = 10V,$ $I_D = 7A$ $V_{DS} = 15V, V_{GS} = 5V,$ $I_D = 7A$		100 65 0.9 5 9 42 21 9.2 5.0 1.5 2.0	135 100 1.6 10 18 68 34 13 7 1.25	pF pF Ω ns ns ns ns nc nC nC NC V



mounted on a 0.5in pad of 2 oz copper

2: Starting T_J = 25°C, L = 1mH, I_{AS} = 8A, V_{DD} = 27V, V_{GS} = 10V. 3: Pulse Test:Pulse Width <300 μ S, Duty Cycle <2%.

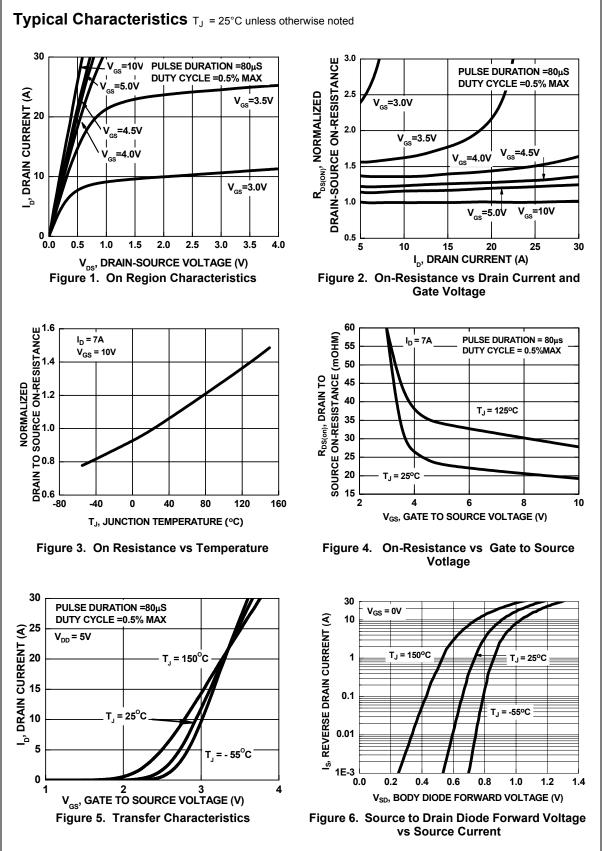
Scale 1 : 1 on letter size paper



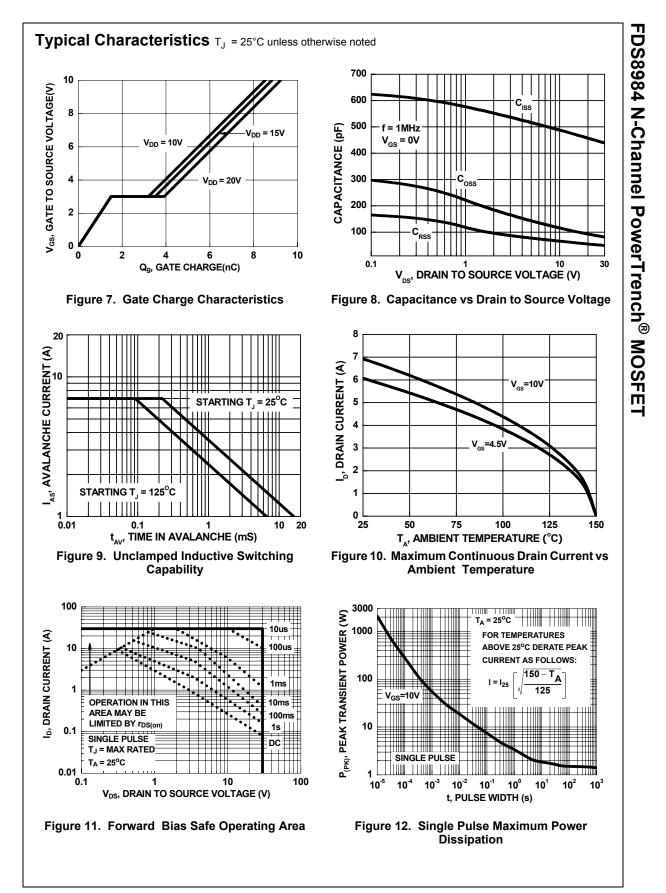
minimun pad

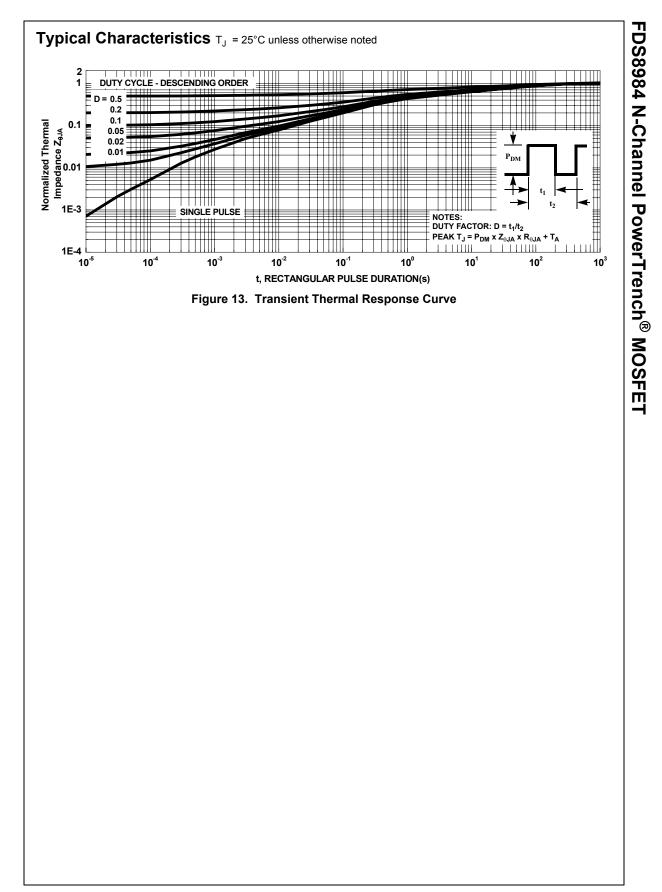
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TinyBoost™

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